

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	11047	(dop\$6 or impurity) near5 (conductive or polysilicon or polySi or ((poly or polycrystalline) adj (Si or silicon))) and (bitline or (bit adj line))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/11 18:07
L2	10067	1 and (contact or via)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/11 17:33
L3	9386	2 and gate	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/11 17:33
L4	9218	3 and (source or drain or transistor or ?MOS or ?FET or MOSFET)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/11 17:34
L5	17985	(dop\$6 or impurity) near5 (conductive or polysilicon or polySi or ((poly or polycrystalline) adj (Si or silicon))) same (drain or source?drain or "S/D")	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/11 17:39
L6	4110	4 and 5	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/11 18:06
L8	3900	6 and (@ad<="20031118" or @rlad<="20031118")	US-PGPUB; USPAT	OR	ON	2005/08/11 18:07

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L2	10067	1 and (contact or via)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/11 17:33
L3	9386	2 and gate	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/11 17:33
L4	9218	3 and (source or drain or transistor or ?MOS or ?FET or MOSFET)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/11 17:34
L5	17985	(dop\$6 or impurity) near5 (conductive or polysilicon or polySi or ((poly or polycrystalline) adj (Si or silicon))) same (drain or source?drain or "S/D")	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/11 17:39
L6	4110	4 and 5	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/11 17:40
L7	85	4 and 5	EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/11 17:40